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APPLICATION NO. FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/602,915 06/25/2003		Kazuhiko Yamamoto	60188-606 1774		
7590 09/01/2004		EXAMINER			
Jack Q. Lever, Jr.			VU, QUANG D		
McDERMOTT, WILL & EMERY 600 Thirteenth Street, N.W.			ART UNIT	PAPER NUMBER	
	DC 20005-3096	2811			

DATE MAILED: 09/01/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		T		T	XV.			
		Applicatio	n No.	Applicant(s)				
Office Action Summary		10/602,91	5	YAMAMOTO, KAZ	UHIKO			
		Examiner		Art Unit				
		Quang D V		2811				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status								
1)🖂	Responsive to communication(s) filed on 21 Ju	une 2004.						
, 	This action is FINAL . 2b) This action is non-final.							
3)	,—							
٠,٣	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims								
5)□ 6)⊠ 7)□	Claim(s) 1,3 and 4 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. Claim(s) is/are allowed. Claim(s) 1,3 and 4 is/are rejected. Claim(s) is/are objected to.							
8)	8) Claim(s) are subject to restriction and/or election requirement.							
Applicat	ion Papers							
9) The specification is objected to by the Examiner.								
10)	10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11)	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority (under 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
Attachmer	at(s)							
_	ce of References Cited (PTO-892)		4) Interview Summa					
	ce of Draftsperson's Patent Drawing Review (PTO-948)		Paper No(s)/Mail	Date I Patent Application (PTO	152\			
	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date)	6) Other:	i i atent Application (PTO	-134)			

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 1, 3 and 4 are rejected under 35 U.S.C. 102(e) as being anticipated by US Patent No. 6,559,014 to Jeon.

Regarding claim 1, Jeon (figure 1) teaches a semiconductor device comprising:

a gate insulating film (110) having a multilayer structure including a zirconium oxide film (110b) and a high dielectric constant film which is formed of an oxide of a metal (110rp) other than zirconium and substantially directly contacting the zirconium oxide film (110b) (column 6, line 28 – column 7, line 4; column 7, lines 37-46; column 7, lines 56-64; column 8, lines 14-17), wherein the high dielectric constant film is a hafnium silicate film (110rp; column 8, lines 14-17).

Regarding claim 3, Jeon teaches the high dielectric constant film contains nitrogen (column 11, lines 38-45).

Regarding claim 4, Jeon teaches the gate insulating film includes a zirconium silicate film (110rp) formed under the zirconium oxide film (110b).

Response to Arguments

Applicant's arguments filed 06/21/04 have been fully considered but they are not persuasive.

It is argued, in page 3 of the remarks, that Jeon does not teach or suggest a high dielectric constant film, which is formed of an oxide of a metal other than zirconium and substantially directly contacting the zirconium oxide film. This argument is not convincing because Jeon teaches a high dielectric constant film which is formed of an oxide of a metal (110rp) other than zirconium and substantially directly contacting the zirconium oxide film (110b) (column 6, line 28 – column 7, line 4; column 7, lines 37-46; column 7, lines 56-64; column 8, lines 14-17), wherein the high dielectric constant film is a hafnium silicate film (110rp; column 8, lines 14-17).

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

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however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quang D Vu whose telephone number is 571-272-1667. The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

qvu August 25, 2004

> DONGHEE KANG PRIMARY EXAMINER

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